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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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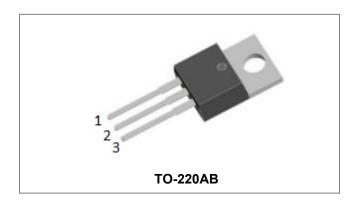








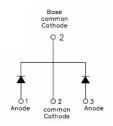
### SDUR3020CT ULTRAFAST RECTIFIER



#### **Applications**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

## **Circuit Diagram**



#### **Features**

- Ultra-Fast switching
- · High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>	_	200	٧
DC Blocking Voltage  Average Rectified Forward Current	V <sub>R</sub>	50% duty cycle @Tc=105°C, rectangular wave form	15(Per Leg) 30(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	200	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25°C @ 30A, Pulse, T <sub>J</sub> = 25°C	1.01 1.19	1.05 -	V
	V <sub>F2</sub>	@ 15A, Pulse, T <sub>J</sub> = 125°C @ 30A, Pulse, T <sub>J</sub> = 125°C	0.91 1.13	0.95 -	V
Reverse Current(Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_{R,} T_J = 25^{\circ}\text{C}$	0.3	10	μA
	I <sub>R2</sub>	$@V_R = \text{rated } V_{R,} T_J = 125^{\circ}\text{C}$	51	500	uA
Reverse Recovery Time(Per Leg)	t <sub>rr1</sub>	I <sub>F</sub> =500mA, I <sub>R</sub> =1A,and I <sub>m</sub> =250mA	25	35	ns
Reverse Recovery Time(Per Leg)	t <sub>rr2</sub>	IF=1A, VR=30V, -diF/dt=200A/us	31	-	ns

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%

- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •



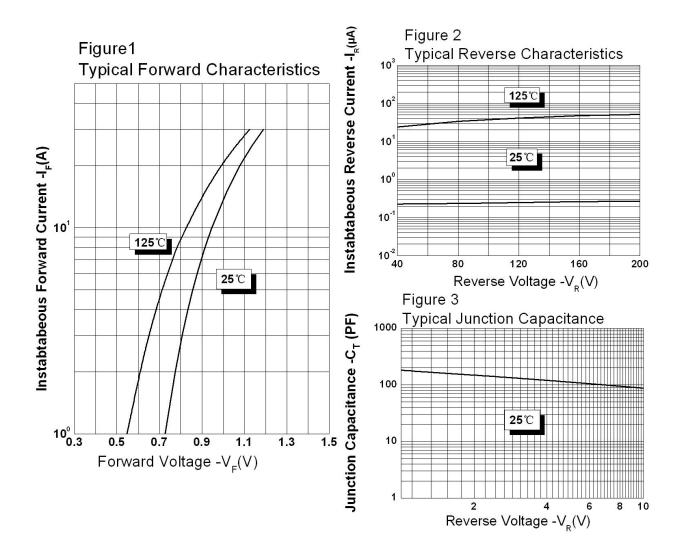




### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> JC	DC operation	1.6	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			

#### **Ratings and Characteristics Curves**



<sup>•</sup> China - Germany - Korea - Singapore - United States •

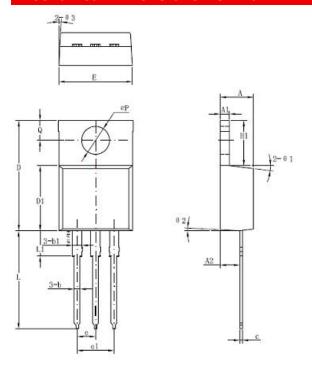
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •





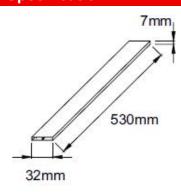


#### **Mechanical Dimensions TO-220AB**

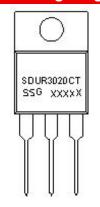


Symbol	Dimensions in millimeters		
_	Min	Typical	Max
Α	4.42	4.57	4.72
A1	1.17	1.27	1.37
A2	2.52	2.69	2.89
b	0.71	0.81	0.96
b1	1.17	1.27	1.37
С	0.31	0.38	0.61
D	14.94	15.24	15.54
D1	8.85	9.00	9.15
E	10.01	10.16	10.31
е		2.54	
e1	4.98	5.06	5.18
H1	6.04	6.24	6.44
L	12.7	13.56	13.80
L1	3.56	3.5	3.96
ФР	3.74	3.84	4.04
Q	2.54	2.74	2.94
Θ1		7°	
Θ2		3°	
Θ3		4°	

### **Tube Specification**



### **Marking Diagram**



Where XXXXX is YYWWL

SDUR = Device Type 30 = Forward Current (30A) 20 = Reverse Voltage(200V)

 $\begin{array}{ll} \mathsf{CT} &= \mathsf{Configuration} \\ \mathsf{SSG} &= \mathsf{SSG} \\ \mathsf{YY} &= \mathsf{Year} \\ \mathsf{WW} &= \mathsf{Week} \\ \mathsf{L} &= \mathsf{Lot} \ \mathsf{Number} \end{array}$ 

Cautions: Molding resin

Epoxy resin UL:94V-0

### **Ordering Information**

Device	Package	Shipping	
SDUR3020CT	TO-220AB (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging Specification.

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